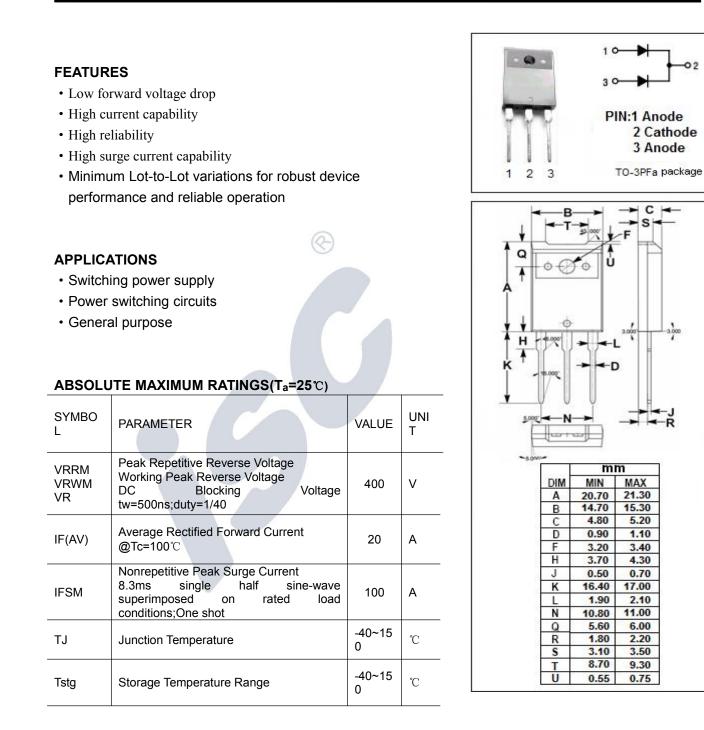


## INCHANGE SEMICONDUCTOR

# **FMD-4206S**

02





## **INCHANGE SEMICONDUCTOR**

# **Ultra fast Rectifier**

# FMD-4206S

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2	°C/W

#### ELECTRICAL CHARACTERISTICS(Ta=25°C) (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
VF	Maximum Instantaneous Forward Voltage	IF=10A	1.4	V
IR	Maximum Instantaneous Reverse Current	VR= V <sub>RWM;</sub>	20	μA
trr	Maximum Reverse Recovery Time	IF =0.5A;90% Recovery point	30	ns

### NOTICE:

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